



# FSCM0565R

## Green Mode Fairchild Power Switch (FPS™)

### Features

- Internal Avalanche Rugged Sense FET
- Low startup current (max 40uA)
- Low power consumption under 1 W at 240VAC & 0.4W load
- Precise Fixed Operating Frequency (66kHz)
- Frequency Modulation for low EMI
- Pulse by Pulse Current Limiting (Adjustable)
- Over Voltage Protection (OVP)
- Over Load Protection (OLP)
- Thermal Shutdown Function (TSD)
- Auto-Restart Mode
- Under Voltage Lock Out (UVLO) with hysteresis
- Built-in Soft Start (15ms)

### Application

- SMPS for VCR, SVR, STB, DVD & DVCD
- Adaptor
- SMPS for LCD Monitor

### Description

The FSCM0565R is an integrated Pulse Width Modulator (PWM) and Sense FET specifically designed for high performance offline Switch Mode Power Supplies (SMPS) with minimal external components. This device is an integrated high voltage power switching regulator which combine an avalanche rugged Sense FET with a current mode PWM control block. The PWM controller includes integrated fixed frequency oscillator, under voltage lockout, leading edge blanking (LEB), optimized gate driver, internal soft start, temperature compensated precise current sources for a loop compensation and self protection circuitry. Compared with discrete MOSFET and PWM controller solution, it can reduce total cost, component count, size and weight simultaneously increasing efficiency, productivity, and system reliability. This device is a basic platform well suited for cost effective designs of flyback converters.

Table 1. Maximum Output Power

OUTPUT POWER TABLE				
PRODUCT	230VAC ±15% <sup>(3)</sup>		85-265VAC	
	Adapt-er <sup>(1)</sup>	Open Frame <sup>(2)</sup>	Adapt-er <sup>(1)</sup>	Open Frame <sup>(2)</sup>
FSCM0565RD	50W	65W	40W	50W
FSCM0765RD	65W	70W	50W	60W
FSCM0565RC	70W	85W	60W	70W
FSCM0765RC	85W	95W	70W	85W

#### Notes:

1. Typical continuous power in a non-ventilated enclosed adaptor measured at 50°C ambient.
2. Maximum practical continuous power in an open frame design at 50°C ambient.
3. 230 VAC or 100/115 VAC with doubler.

### Typical Circuit

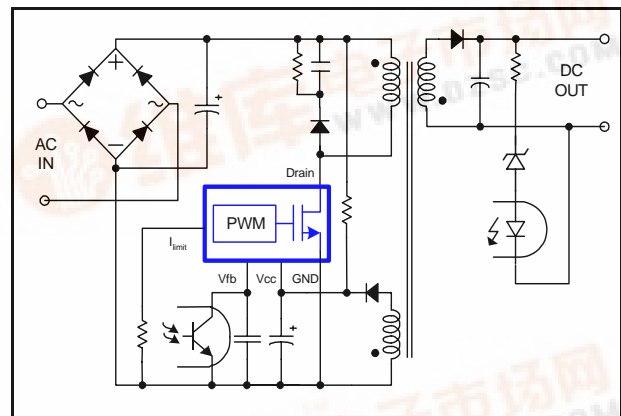


Figure 1. Typical Flyback Application



## Pin Definitions

Pin Number	Pin Name	Pin Function Description
1	Drain	This pin is the high voltage power SenseFET drain. It is designed to drive the transformer directly.
2	GND	This pin is the control ground and the SenseFET source.
3	Vcc	This pin is the positive supply voltage input. Initially, During start up, the power is supplied through the startup resistor from DC link. When Vcc reaches 12V, the power is supplied from auxiliary transformer winding.
4	Feedback (FB)	This pin is internally connected to the inverting input of the PWM comparator. The collector of an optocoupler is typically tied to this pin. For stable operation, a capacitor should be placed between this pin and GND. If the voltage of this pin reaches 6.0V, the over load protection is activated resulting in shutdown of the FPS.
5	I_limit	This pin is for the pulse by pulse current limit level programming. By using a resistor to GND on this pin, the current limit level can be changed. If this pin is left floating, the typical current limit will be 2.5A.

## Pin Configuration

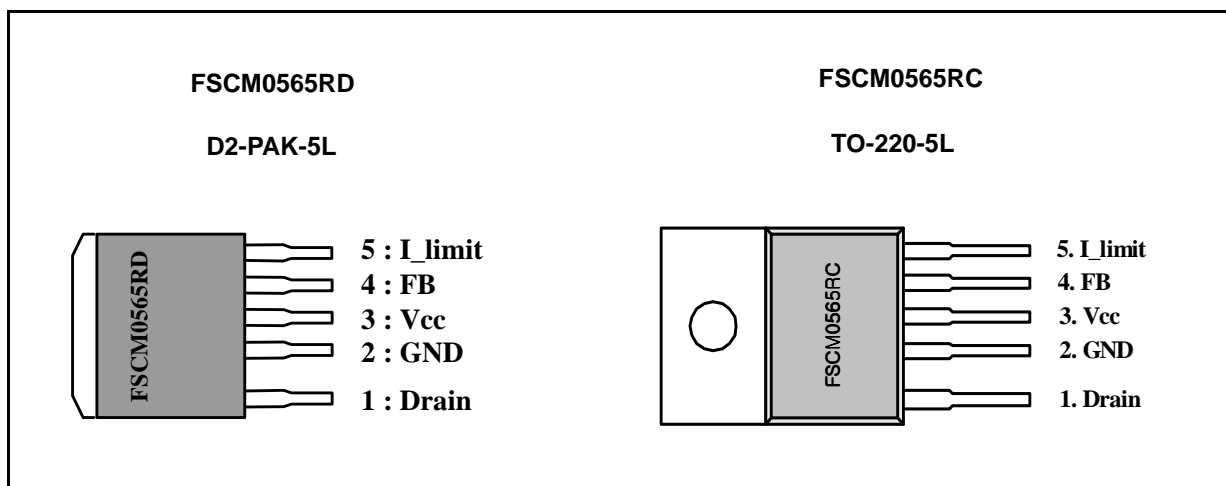


Figure 3. Pin Configuration (Top View)

## Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source (GND) Voltage <sup>(1)</sup>	V <sub>DSS</sub>	650	V
Drain-Gate Voltage (R <sub>GS</sub> =1MΩ)	V <sub>DGR</sub>	650	V
Gate-Source (GND) Voltage	V <sub>GS</sub>	±30	V
Drain Current Pulsed <sup>(2)</sup>	I <sub>DM</sub>	20	ADC
Continuous Drain Current (TO-220) @ T <sub>c</sub> = 25°C	I <sub>D</sub>	5	ADC
@ T <sub>C</sub> =100°C	I <sub>D</sub>	3.2	ADC
Continuous Drain Current (D2-PAK) @ T <sub>c</sub> = 25°C	I <sub>D</sub>	2.9	ADC
@ T <sub>C</sub> =100°C	I <sub>D</sub>	1.9	ADC
Supply Voltage	V <sub>CC</sub>	20	V
Analog Input Voltage Range	V <sub>FB</sub>	-0.3 to V <sub>CC</sub>	V
Total Power Dissipation (D2-PAK)	P <sub>D</sub>	75	W
	Derating	0.6	W/°C
Total Power Dissipation (TO-220)	P <sub>D</sub>	120	W
	Derating	0.96	W/°C
Operating Junction Temperature	T <sub>J</sub>	Internally limited	°C
Operating Ambient Temperature	T <sub>A</sub>	-25 to +85	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C
ESD Capability, HBM Model (All pins excepts for V <sub>str</sub> and V <sub>fb</sub> )	-	2.0 (V <sub>cc</sub> -V <sub>fb</sub> =1.0kV)	kV
ESD Capability, Machine Model (All pins excepts for V <sub>str</sub> and V <sub>fb</sub> )	-	300 (V <sub>cc</sub> -V <sub>fb</sub> =100V)	V

### Notes:

1. T<sub>j</sub> = 25°C to 150°C
2. Repetitive rating: Pulse width limited by maximum junction temperature
3. L = 30mH, V<sub>DD</sub> = 50V, R<sub>G</sub> = 25Ω, starting T<sub>j</sub> = 25°C
4. L = 13uH, starting T<sub>j</sub> = 25°C

## Electrical Characteristics

(Ta = 25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
<b>Sense FET SECTION</b>						
Drain source breakdown voltage	BVDSS	VGS = 0V, ID = 250μA	650	-	-	V
Zero gate voltage drain current	IDSS	VDS = Max, Rating VGS = 0V	-	-	500	μA
Static drain source on resistance	RDS(ON)	VGS = 10V, ID = 2.3A	-	1.76	2.2	Ω
Output capacitance	COSS	VGS = 0V, VDS = 25V, f = 1MHz	-	78	-	pF
Turn on delay time	TD(ON)	VDD= 325V, ID= 5A (MOSFET switching time is essentially independent of operating temperature)	-	22	-	ns
Rise time	TR		-	52	-	
Turn off delay time	TD(OFF)		-	95	-	
Fall time	TF		-	50	-	
<b>CONTROL SECTION</b>						
Initial frequency	FOSC	VCC=14V, VFB=5V	60	66	72	kHz
Modulated frequency range	ΔFmod	-	-	±3	-	kHz
Frequency modulation cycle	Tmod	-	-	4	-	ms
Voltage stability	FSTABLE	10V≤VCC≤17V	0	1	3	%
Temperature stability	ΔFOSC	-25°C≤Ta≤+85°C	-	±5	±10	%
Maximum duty cycle	DMAX	-	75	80	85	%
Minimum duty cycle	DMIN	-	-	-	0	%
Start threshold voltage	VSTART	VFB=GND	11	12	13	V
Stop threshold voltage	VSTOP	VFB=GND	7	8	9	V
Feedback source current	IFB	VFB=GND	0.7	0.9	1.1	mA
Soft-start time	TSS	-	10	15	20	ms
<b>BURST MODE SECTION</b>						
Burst Mode Voltages	VBH	Vcc=14V	0.4	0.5	0.6	V
	VBL	Vcc=14V	0.24	0.3	0.36	V

PROTECTION SECTION						
Peak current limit	I <sub>LIM</sub>	V <sub>CC</sub> =14V, V <sub>FB</sub> =5V	2.2	2.5	2.8	A
Over voltage protection	VOVP	-	18	19	20	V
Thermal shutdown temperature	T <sub>SD</sub>		130	145	160	°C
Shutdown delay current	I <sub>DELAY</sub>	V <sub>FB</sub> =4V	3.5	5.3	7	μA
Shutdown feedback voltage	V <sub>SD</sub>	V <sub>FB</sub> ≥5.5V	5.5	6	6.5	V
TOTAL DEVICE SECTION						
Startup current	I <sub>start</sub>		-	20	40	μA
Operating supply current	I <sub>OP(MIN)</sub>	V <sub>CC</sub> =10V, V <sub>FB</sub> =0V	-	2.5	5	mA
	I <sub>OP(MAX)</sub>	V <sub>CC</sub> =20V, V <sub>FB</sub> =0V				

**Notes:**

1. Pulse test : Pulse width ≤ 300μS, duty ≤ 2%
2. These parameters, although guaranteed at the design, are not tested in mass production.
3. These parameters, although guaranteed, are tested in EDS (wafer test) process.
4. These parameters indicate the inductor current.
5. This parameter is the current flowing into the control IC.

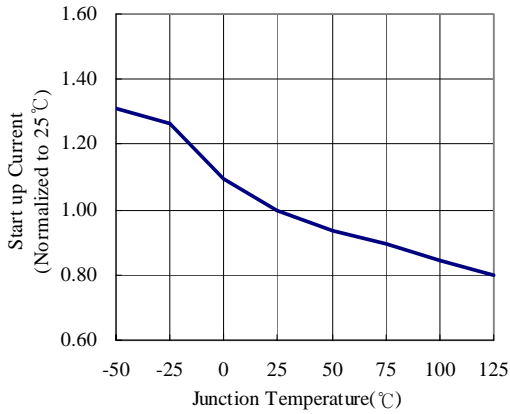
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**Comparison Between FSDM0565RB and FSCM0565R**

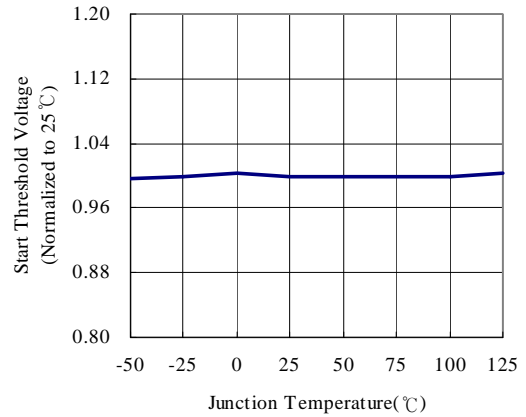
Function	FSDM0565RB	FSCM0565R
Frequency modulation	N.A.	Available <ul style="list-style-type: none"><li>• Modulated frequency range (<math>DF_{mod}</math>) = <math>\pm 3\text{kHz}</math></li><li>• Frequency modulation cycle (<math>T_{mod}</math>) = 4ms</li></ul>
Pulse-by-pulse current limit	<ul style="list-style-type: none"><li>• Internally fixed (2.25A)</li></ul>	<ul style="list-style-type: none"><li>• Programmable using external resistor (2.5A max)</li></ul>
Internal Startup Circuit	<ul style="list-style-type: none"><li>• Available</li></ul>	<ul style="list-style-type: none"><li>• N.A. (Requires startup resistor)</li><li>• Startup current : 40uA (max)</li></ul>

## Typical Performance Characteristics

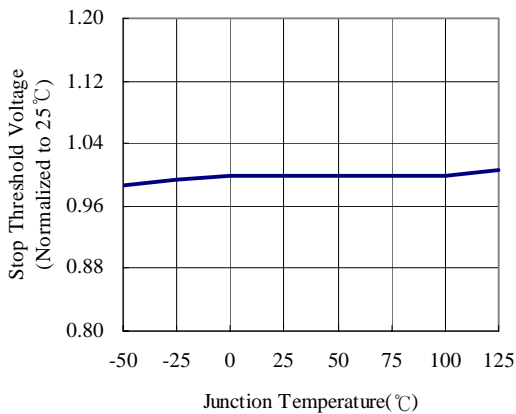
(These Characteristic Graphs are Normalized at Ta= 25°C)



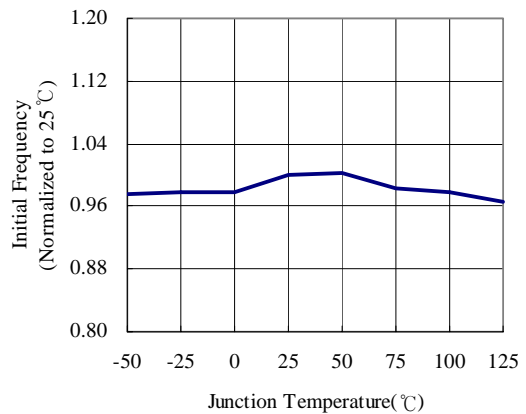
**Startup Current vs. Temp**



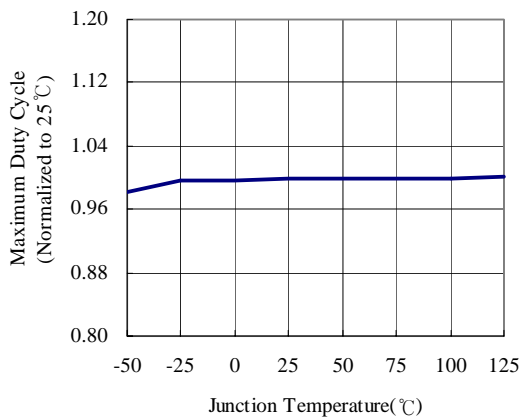
**Start Threshold Voltage vs. Temp**



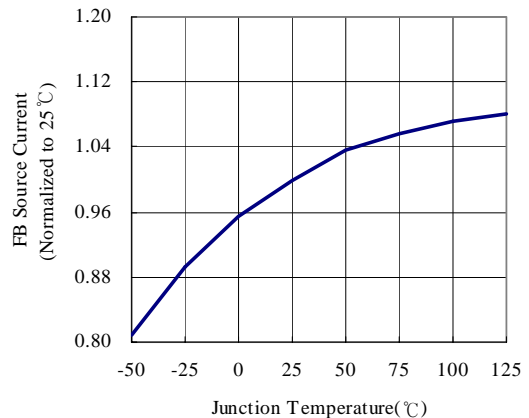
**Stop Threshold Voltage vs. Temp**



**Initial Frequency vs. Temp**



**Maximum Duty Cycle vs. Temp**

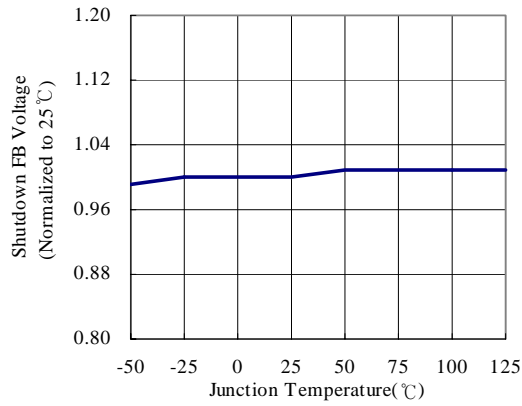


**Feedback Source Current vs. Temp**

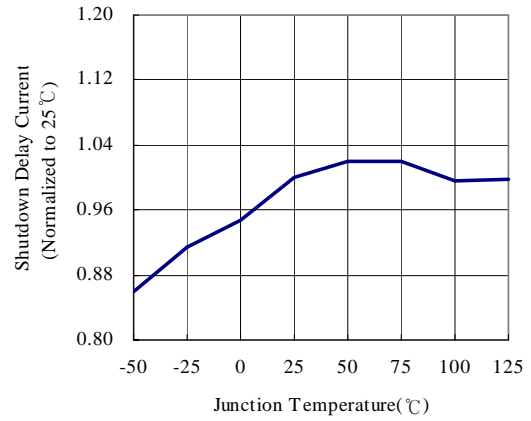


## Typical Performance Characteristics (Continued)

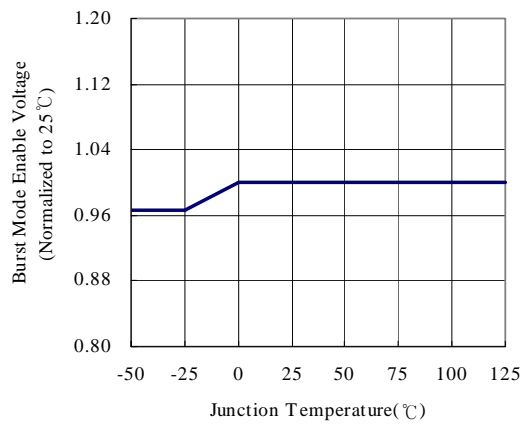
(These Characteristic Graphs are Normalized at Ta= 25°C)



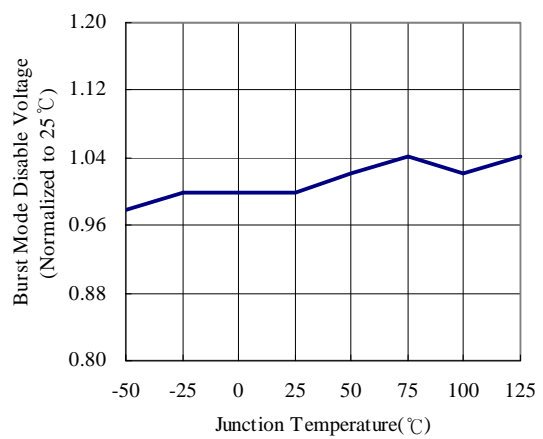
ShutDown Feedback Voltage vs. Temp



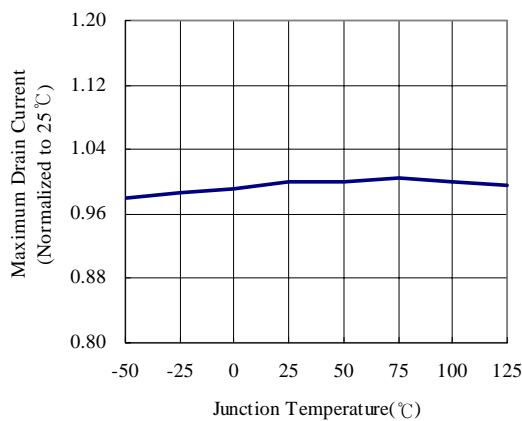
ShutDown Delay Current vs. Temp



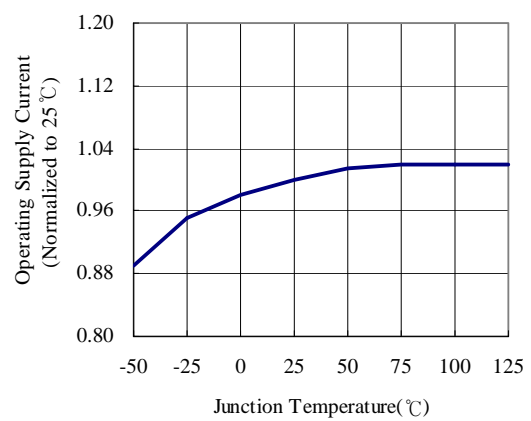
Burst Mode Enable Voltage vs. Temp



Burst Mode Disable Voltage vs. Temp



Mavimum Drain Current vs. Temp



Operating Supply Current vs. Temp

## Functional Description

**1. Startup :** Figure 4 shows the typical startup circuit and transformer auxiliary winding for FSCM0565R application. Before FSCM0565R begins switching, FSCM0565R consumes only startup current (typically 25uA) and the current supplied from the DC link supply current consumed by FPS ( $I_{cc}$ ) and charges the external capacitor ( $C_a$ ) that is connected to the Vcc pin. When Vcc reaches start voltage of 12V ( $V_{START}$ ), FSCM0565R begins switching, and the current consumed by FSCM0565R increases to 3mA. Then, FSCM0565R continues its normal switching operation and the power required for this device is supplied from the transformer auxiliary winding, unless Vcc drops below the stop voltage of 8V ( $V_{STOP}$ ). To guarantee the stable operation of the control IC, Vcc has under voltage lockout (UVLO) with 4V hysteresis. Figure 5 shows the relation between the current consumed by FPS ( $I_{cc}$ ) and the supply voltage (Vcc).

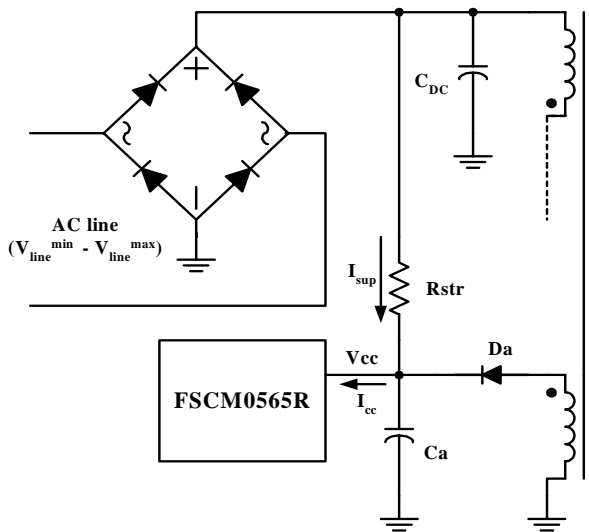


Figure 4. Startup circuit

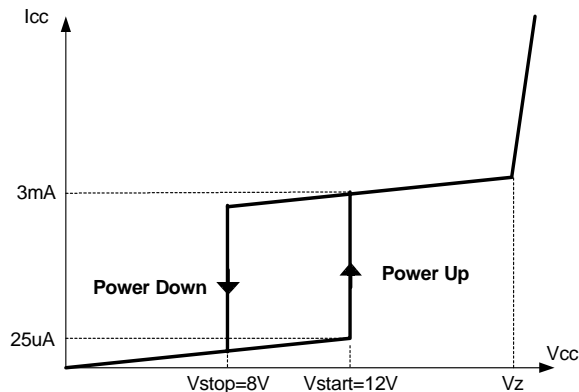


Figure 5. Relation between operating supply current and Vcc voltage

The minimum current supplied through the startup resistor is given by

$$I_{sup}^{min} = (\sqrt{2} \cdot V_{line}^{min} - V_{start}) \cdot \frac{1}{R_{str}}$$

where  $V_{line}^{min}$  is the minimum input voltage,  $V_{start}$  is the start voltage (12V) and  $R_{str}$  is the startup resistor. The startup resistor should be chosen so that  $I_{sup}^{min}$  is larger than the maximum startup current (40uA). If not, Vcc can not be charged to the start voltage and FPS will fail to start up.

**2. Feedback Control :** FSCM0565R employs current mode control, as shown in Figure 6. An opto-coupler (such as the H11A817A) and shunt regulator (such as the KA431) are typically used to implement the feedback network. Comparing the feedback voltage with the voltage across the Rsense resistor makes it possible to control the switching duty cycle. When the reference pin voltage of the KA431 exceeds the internal reference voltage of 2.5V, the H11A817A LED current increases, thus pulling down the feedback voltage and reducing the duty cycle. This event typically happens when the input voltage is increased or the output load is decreased.

**2.1 Pulse-by-pulse current limit:** Because current mode control is employed, the peak current through the Sense FET is determined by the inverting input of PWM comparator ( $V_{fb}^*$ ) as shown in Figure 6. When the current through the opto transistor is zero and the current limit pin (#5) is left floating, the feedback current source ( $I_{FB}$ ) of 0.9mA flows only through the internal resistor ( $R+2.5R=2.8k$ ). In this case, the cathode voltage of diode D2 and the peak drain current have maximum values of 2.5V and 2.5A, respectively. The pulse-by-pulse current limit can be adjusted using a resistor to GND on current limit pin (#5). The current limit level using an external resistor ( $R_{LIM}$ ) is given by

$$I_{LIM} = \frac{R_{LIM} \cdot 2.5A}{2.8k\Omega + R_{LIM}}$$

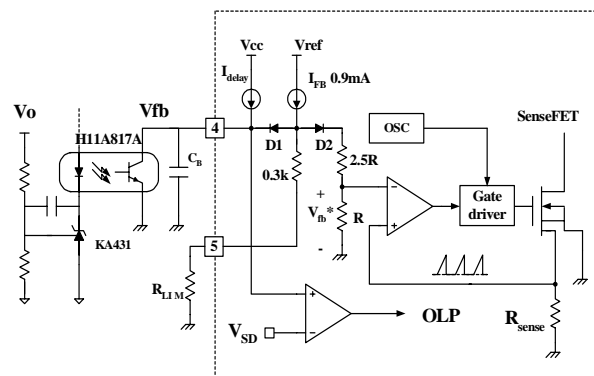


Figure 6. Pulse width modulation (PWM) circuit

**2.2 Leading edge blanking (LEB) :** At the instant the internal Sense FET is turned on, there usually exists a high current spike through the Sense FET, caused by primary-side capacitance and secondary-side rectifier reverse recovery. Excessive voltage across the Rsense resistor would lead to incorrect feedback operation in the current mode PWM control. To counter this effect, the FSCM0565R employs a leading edge blanking (LEB) circuit. This circuit inhibits the PWM comparator for a short time ( $T_{LEB}$ ) after the Sense FET is turned on.

**3. Protection Circuit :** The FSCM0565R has several self protective functions such as over load protection (OLP), over voltage protection (OVP) and thermal shutdown (TSD). Because these protection circuits are fully integrated into the IC without external components, the reliability can be improved without increasing cost. Once the fault condition occurs, switching is terminated and the Sense FET remains off. This causes Vcc to fall. When Vcc reaches the UVLO stop voltage of 8V, the current consumed by FSCM0565R reduces to the startup current (typically 25uA) and the current supplied from the DC link charges the external capacitor ( $C_a$ ) that is connected to the Vcc pin. When Vcc reaches the start voltage of 12V, FSCM0565R resumes its normal operation. In this manner, the auto-restart can alternately enable and disable the switching of the power Sense FET until the fault condition is eliminated (see Figure 7).

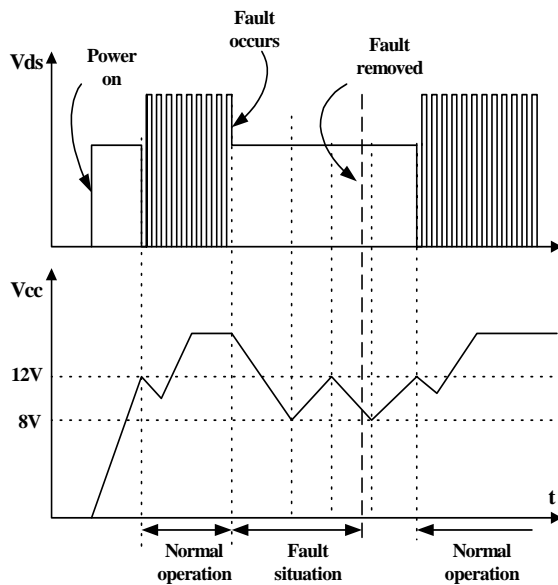


Figure 7. Auto restart operation

**3.1 Over Load Protection (OLP) :** Overload is defined as the load current exceeding a pre-set level due to an unexpected event. In this situation, the protection circuit should be activated in order to protect the SMPS. However,

even when the SMPS is in the normal operation, the over load protection circuit can be activated during the load transition. In order to avoid this undesired operation, the over load protection circuit is designed to be activated after a specified time to determine whether it is a transient situation or an overload situation. Because of the pulse-by-pulse current limit capability, the maximum peak current through the Sense FET is limited, and therefore the maximum input power is restricted with a given input voltage. If the output consumes beyond this maximum power, the output voltage ( $V_o$ ) decreases below the set voltage. This reduces the current through the opto-coupler LED, which also reduces the opto-coupler transistor current, thus increasing the feedback voltage ( $V_{fb}$ ). If  $V_{fb}$  exceeds 2.5V, D1 is blocked and the 5.3uA current source ( $I_{delay}$ ) starts to charge  $C_B$  slowly up to  $V_{cc}$ . In this condition,  $V_{fb}$  continues increasing until it reaches 6V, when the switching operation is terminated as shown in Figure 8. The delay time for shutdown is the time required to charge  $C_B$  from 2.5V to 6.0V with 5.3uA ( $I_{delay}$ ). In general, a 10 ~ 50 ms delay time is typical for most applications.

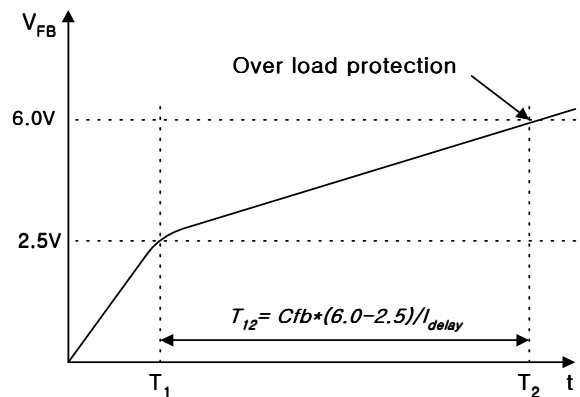


Figure 8. Over load protection

**3.2 Over voltage Protection (OVP) :** If the secondary side feedback circuit were to malfunction or a solder defect caused an open in the feedback path, the current through the opto-coupler transistor becomes almost zero. Then,  $V_{fb}$  climbs up in a similar manner to the over load situation, forcing the preset maximum current to be supplied to the SMPS until the over load protection is activated. Because more energy than required is provided to the output, the output voltage may exceed the rated voltage before the over load protection is activated, resulting in the breakdown of the devices in the secondary side. In order to prevent this situation, an over voltage protection (OVP) circuit is employed. In general,  $V_{cc}$  is proportional to the output voltage and the FSCM0565R uses  $V_{cc}$  instead of directly monitoring the output voltage. If  $V_{cc}$  exceeds 19V, an OVP circuit is activated resulting in the termination of the switching operation. In order to avoid undesired activation of OVP during normal operation,  $V_{cc}$  should be designed to be below 19V.

**3.3 Thermal Shutdown (TSD) :** The Sense FET and the control IC are built in one package. This makes it easy for the control IC to detect the heat generation from the Sense FET. When the temperature exceeds approximately 145°C, the thermal protection is triggered resulting in shutdown of FPS.

**4. Frequency Modulation :** EMI reduction can be accomplished by modulating the switching frequency of a switched power supply. Frequency modulation can reduce EMI by spreading the energy over a wider frequency range than the band width measured by the EMI test equipment. The amount of EMI reduction is directly related to the depth of the reference frequency. As can be seen in Figure 9, the frequency changes from 63KHz to 69KHz in 4ms.

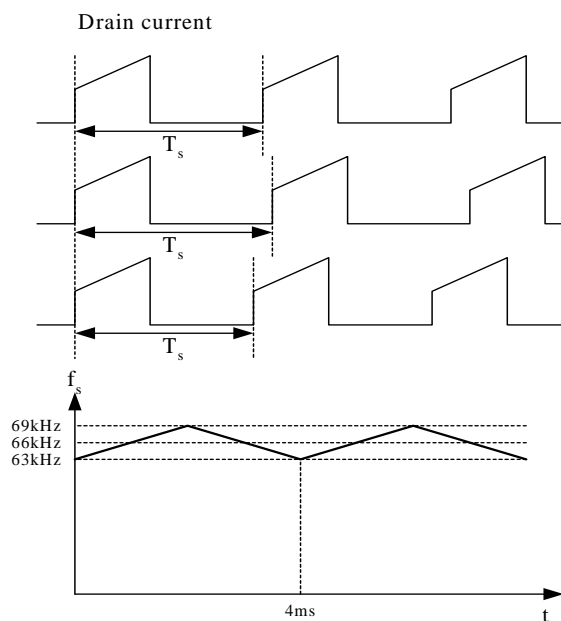


Figure 9. Frequency Modulation

**5. Soft Start :** The FSCM0565R has an internal soft start circuit that increases PWM comparator inverting input voltage together with the Sense FET current slowly after it starts up. The typical soft start time is 15msec. The pulse width to the power switching device is progressively increased to establish the correct working conditions for transformers, rectifier diodes and capacitors. The voltage on the output capacitors is progressively increased with the intention of smoothly establishing the required output voltage. It also helps to prevent transformer saturation and reduce the stress on the secondary diode during startup.

**6. Burst operation :** In order to minimize power dissipation in standby mode, the FSCM0565R enters into burst mode operation at light load condition. As the load decreases, the feedback voltage decreases. As shown in Figure 10, the

device automatically enters into burst mode when the feedback voltage drops below  $V_{BL}$  (300mV). At this point switching stops and the output voltages start to drop at a rate dependent on standby current load. This causes the feedback voltage to rise. Once it passes  $V_{BH}$  (500mV) switching resumes. The feedback voltage then falls and the process repeats. Burst mode operation alternately enables and disables switching of the power Sense FET thereby reducing switching loss in standby mode.

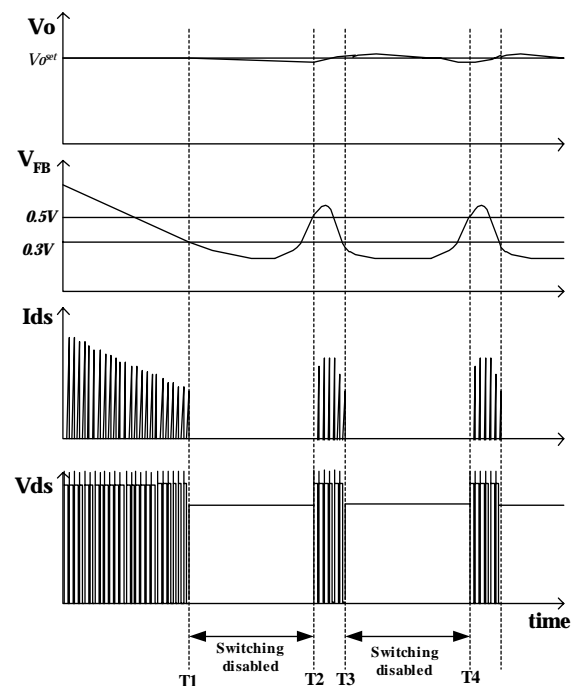
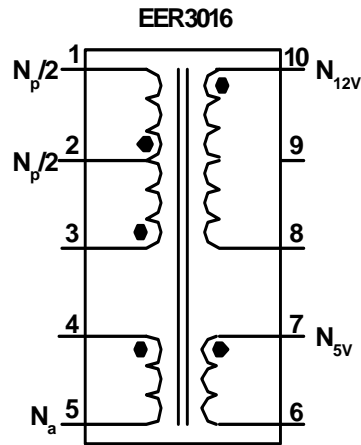


Figure 10. Waveforms of burst operation



## 2. Transformer Schematic Diagram



## 3. Winding Specification

No	Pin (s→f)	Wire	Turns	Winding Method
Na	4 → 5	0.2 <sup>φ</sup> × 1	8	Center Winding
Insulation: Polyester Tape t = 0.050mm, 2Layers				
Np/2	2 → 1	0.4 <sup>φ</sup> × 1	18	Solenoid Winding
Insulation: Polyester Tape t = 0.050mm, 2Layers				
N12V	10 → 8	0.3 <sup>φ</sup> × 3	7	Center Winding
Insulation: Polyester Tape t = 0.050mm, 2Layers				
N5V	7 → 6	0.3 <sup>φ</sup> × 3	3	Center Winding
Insulation: Polyester Tape t = 0.050mm, 2Layers				
Np/2	3 → 2	0.4 <sup>φ</sup> × 1	18	Solenoid Winding
Outer Insulation: Polyester Tape t = 0.050mm, 2Layers				

## 4. Electrical Characteristics

	Pin	Specification	Remarks
Inductance	1 - 3	570uH ± 10%	100kHz, 1V
Leakage Inductance	1 - 3	10uH Max	2 <sup>nd</sup> all short

## 5. Core & Bobbin

Core : EER 3016

Bobbin : EER3016

Ae(mm<sup>2</sup>) : 96

## 6.Demo Circuit Part List

Part	Value	Note	Part	Value	Note
<b>Fuse</b>			C301	4.7nF	Polyester Film Cap.
F101	2A/250V				
<b>NTC</b>			<b>Inductor</b>		
RT101	5D-9		L201	5uH	Wire 1.2mm
<b>Resistor</b>			L202	5uH	Wire 1.2mm
R101	560K	1W			
R102	500K	1/4W			
R103	56K	2W			
R104	5	1/4W	<b>Diode</b>		
R105	500K	1/4W	D101	UF4007	
R106	10K	1/4W	D102	TVR10G	
R201	1K	1/4W	D201	MBRF1045	
R202	10K	1/4W	D202	MBRF10100	
R203	1.2K	1/4W	ZD101	22V Zener diode	
R204	5.6K	1/4W	ZD102	10V Zener diode	
R205	5.6K	1/4W	<b>Bridge Diode</b>		
			BD101	2KBP06M 3N257	Bridge Diode
<b>Capacitor</b>					
C101	220nF/275VAC	Box Capacitor	<b>Line Filter</b>		
C102	220nF/275VAC	Box Capacitor	LF101	23mH	Wire 0.4mm
C103	100uF/400V	Electrolytic Capacitor	<b>IC</b>		
C104	10nF/1kV	Ceramic Capacitor	IC101	FSCM0565RC	FPS™(7A,650V)
C105	22uF/50V	Electrolytic Capacitor	IC201	KA431(TL431)	Voltage reference
C106	47nF/50V	Ceramic Capacitor	IC301	H11A817A	Opto-coupler
C201	1000uF/25V	Electrolytic Capacitor			
C202	1000uF/25V	Electrolytic Capacitor			
C203	1000uF/10V	Electrolytic Capacitor			
C204	1000uF/10V	Electrolytic Capacitor			
C205	47nF/50V	Ceramic Capacitor			

### 7. Layout

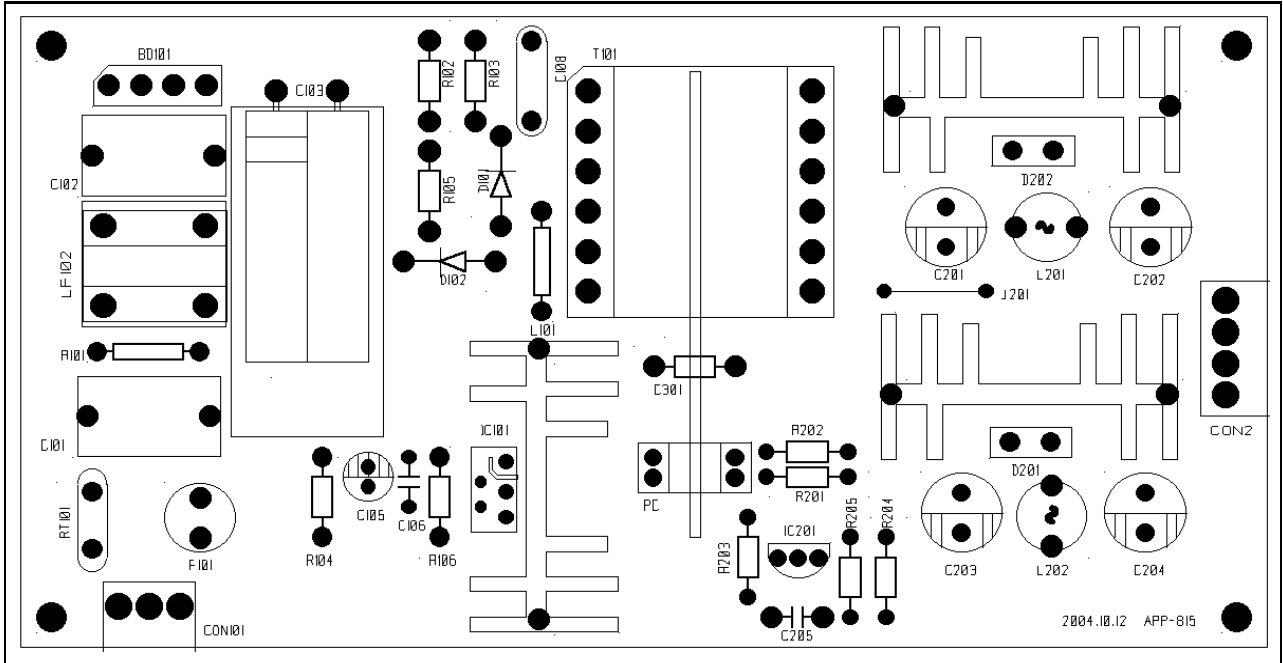


Figure 11. Layout Considerations for FSCM0565RC

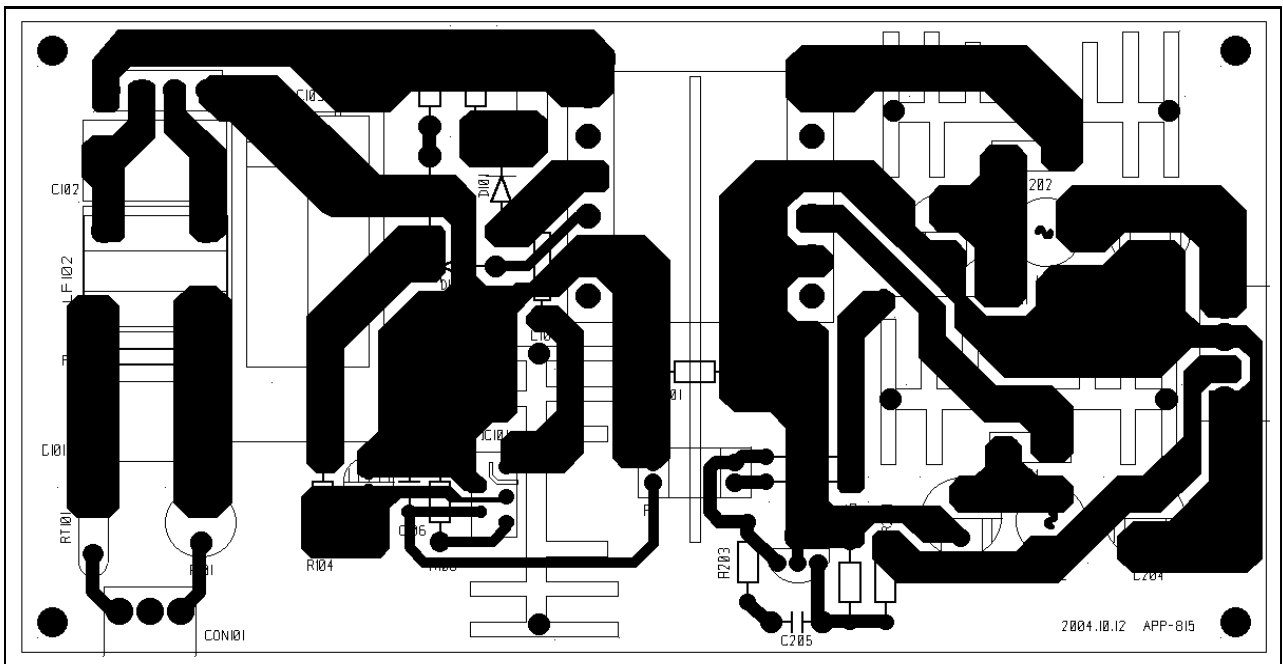


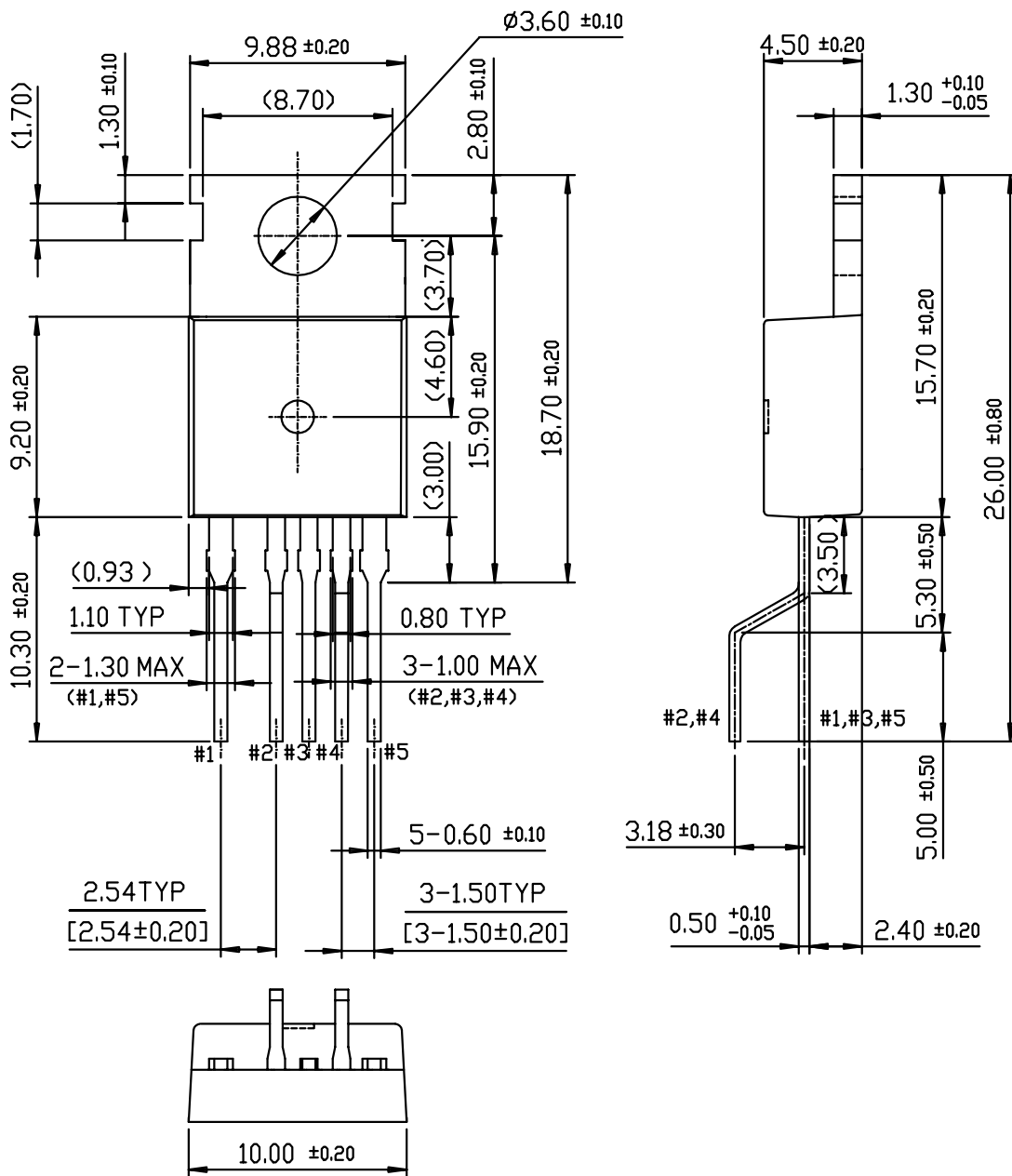
Figure 12. Layout Considerations for FSCM0565RC





Package Dimensions (Continued)

TO-220-5L(Forming)



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**Ordering Information**

<b>Product Number</b>	<b>Package</b>	<b>Marking Code</b>	<b>BVdss</b>	<b>Rds(on)Max.</b>
FSCM0565RD	D2-PAK-5L	CM0565RD	650V	2.2 $\Omega$
FSCM0565RCYDTU	TO-220-5L	CM0565RC	650V	2.2 $\Omega$

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